# **NL17SH34**

# **Single Buffer**

The NL17SH34 MiniGate<sup>™</sup> is an advanced high-speed CMOS Buffer in ultra-small footprint.

The NL17SH34 input structure provides protection when voltages up to 7.0 V are applied, regardless of the supply voltage.

#### **Features**

- High Speed:  $t_{PD} = 3.5$  ns (Typ) at  $V_{CC} = 5.0$  V
- Low Power Dissipation:  $I_{CC} = 1.0 \ \mu A$  (Max) at  $T_A = 25^{\circ}C$
- Power Down Protection Provided on Inputs
- Balanced Propagation Delays

IN A

GND

NC 3

IN A

2

- Overvoltage Tolerant (OVT) Input Pins
- Ultra-Small Package
- These are Pb-Free and Halide-Free Devices

 $\bigcirc$ 

5 V<sub>CC</sub>

4

Figure 1. Pinout (Top View)

1

Figure 2. Logic Symbol

OUT Y

OUT Y



### **ON Semiconductor®**

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#### MARKING DIAGRAM



2



= Specific Device Code (Rotated 90°)

SOT-953

= Month Code Μ

| PIN ASSIGNMENT |                 |  |  |  |  |  |
|----------------|-----------------|--|--|--|--|--|
| 1              | IN A            |  |  |  |  |  |
| 2              | GND             |  |  |  |  |  |
| 3              | NC              |  |  |  |  |  |
| 4              | OUT Y           |  |  |  |  |  |
| 5              | V <sub>CC</sub> |  |  |  |  |  |

#### **FUNCTION TABLE**

| A Input | Y Output |
|---------|----------|
| L       | L        |
| Н       | Н        |

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

#### **MAXIMUM RATINGS**

| Symbol               | Param                                     | neter  | Value  | Unit |
|----------------------|---|--|--|------|
| V <sub>CC</sub>      | DC Supply Voltage                         |  | -0.5 to +7.0                                 | V    |
| V <sub>IN</sub>      | DC Input Voltage                          |  | -0.5 to +7.0                                 | V    |
| V <sub>OUT</sub>     | DC Output Voltage                         | V <sub>IN</sub> = 0<br>High or Low State   | -0.5 to +7.0<br>-0.5 to V <sub>CC</sub> +0.5 | V    |
| I <sub>IK</sub>      | DC Input Diode Current                    | V <sub>IN</sub> < GND  | -20  | mA   |
| I <sub>OK</sub>      | DC Output Diode Current                   | $V_{OUT}$ < GND, $V_{OUT}$ > $V_{CC}$  | ±20  | mA   |
| I <sub>OUT</sub>     | DC Output Source/Sink Current             |  | ±25  | mA   |
| I <sub>CC</sub>      | DC Supply Current per Supply Pin          |  | 50   | mA   |
| T <sub>STG</sub>     | Storage Temperature Range                 |  | -65 to +150                                  | °C   |
| ΤL                   | Lead Temperature, 1 mm from Case for 10 S | Seconds  | 260  | °C   |
| TJ                   | Junction Temperature Under Bias           |  | +150   | °C   |
| MSL                  | Moisture Sensitivity                      |  | Level 1                                      |      |
| F <sub>R</sub>       | Flammability Rating                       | Oxygen Index: 28 to 34   | UL 94 V-0 @ 0.125 in                         |      |
| V <sub>ESD</sub>     | ESD Withstand Voltage                     | Human Body Model (Note 2)<br>Machine Model (Note 3)<br>Charged Device Model (Note 4) | >2000<br>>200<br>N/A                         | V    |
| I <sub>LATCHUP</sub> | Latchup Performance Abo                   | ve V <sub>CC</sub> and Below GND at 125°C (Note 5)                                   | ±100   | mA   |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.
Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2-ounce copper trace with no air flow.

2. Tested to EIA/JESD22-A114-A.

3. Tested to EIA/JESD22-A115-A.

4. Tested to JESD22-C101-A.

5. Tested to EIA/JESD78.

#### **RECOMMENDED OPERATING CONDITIONS**

| Symbol                | Characteristics   | Min  | Max    | Unit            |      |
|-----------------------|---|--|--------|-----------------|------|
| V <sub>CC</sub>       | Positive DC Supply Voltage  | 1.65   | 5.5    | V               |      |
| V <sub>IN</sub>       | Digital Input Voltage   | 0.0  | 5.5    | V               |      |
| V <sub>OUT</sub>      | Output Voltage  |  | 0.0    | V <sub>CC</sub> | V    |
| T <sub>A</sub>        | Operating Temperature Range   |  | -55    | +125            | °C   |
| $\Delta t / \Delta V$ | Input Transition Rise or Fail Rate V <sub>C</sub><br>V <sub>C</sub> | $_{\rm C} = 3.3 \text{ V} \pm 0.3 \text{ V}$<br>$_{\rm C} = 5.0 \text{ V} \pm 0.5 \text{ V}$ | 0<br>0 | 100<br>20       | ns/V |

#### DC ELECTRICAL CHARACTERISTICS

|                 |                              |  | V <sub>cc</sub>   | Т                         | A = 25°           | C                         | T <sub>A</sub> ≤          | 85°C                      | -55°C 1           | to 125°C                  |      |
|-----------------|------------------------------|--|-------------------|---------------------------|-------------------|---------------------------|---------------------------|---------------------------|-------------------|---------------------------|------|
| Symbol          | Parameter                    | Test Conditions  | (V)               | Min                       | Тур               | Max                       | Min                       | Max                       | Min               | Max                       | Unit |
| V <sub>IH</sub> | High-Level Input<br>Voltage  |  | 1.65 to<br>2.0    | 0.75 x<br>V <sub>CC</sub> |                   |                           | 0.75 x<br>V <sub>CC</sub> |                           |                   |                           | V    |
|                 |                              |  | 2.3 to<br>5.5     | 0.70 x<br>V <sub>CC</sub> |                   |                           | 0.70 x<br>V <sub>CC</sub> |                           |                   |                           |      |
| V <sub>IL</sub> | Low-Level Input<br>Voltage   |  | 1.65 to<br>2.0    |                           |                   | 0.25 x<br>V <sub>CC</sub> |                           | 0.25 x<br>V <sub>CC</sub> |                   | 0.25 x<br>V <sub>CC</sub> | V    |
|                 |                              |  | 2.3 to<br>5.5     |                           |                   | 0.30 x<br>V <sub>CC</sub> |                           | 0.30 x<br>V <sub>CC</sub> |                   | 0.30 x<br>V <sub>CC</sub> |      |
| V <sub>OH</sub> | High-Level Output<br>Voltage | $V_{IN} = V_{IH} \text{ or } V_{IL}$<br>$I_{OH} = -50 \ \mu A$                         | 2.0<br>3.0<br>4.5 | 1.9<br>2.9<br>4.4         | 2.0<br>3.0<br>4.5 |                           | 1.9<br>2.9<br>4.4         |                           | 1.9<br>2.9<br>4.4 |                           | V    |
|                 |                              | $V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OH} = -4 \text{ mA}$ $I_{OH} = -8 \text{ mA}$ | 3.0<br>4.5        | 2.58<br>3.94              |                   |                           | 2.48<br>3.80              |                           | 2.34<br>3.66      |                           |      |
| V <sub>OL</sub> | Low-Level Output<br>Voltage  | $V_{IN} = V_{IH} \text{ or } V_{IL}$<br>$I_{OL} = 50 \ \mu A$                          | 2.0<br>3.0<br>4.5 |                           | 0.0<br>0.0<br>0.0 | 0.1<br>0.1<br>0.1         |                           | 0.1<br>0.1<br>0.1         |                   | 0.1<br>0.1<br>0.1         | V    |
|                 |                              | $V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 4 \text{ mA}$ $I_{OL} = 8 \text{ mA}$   | 3.0<br>4.5        |                           |                   | 0.36<br>0.36              |                           | 0.44<br>0.44              |                   | 0.52<br>0.52              |      |
| I <sub>IN</sub> | Input Leakage Current        | $V_{IN} = 5.5 \text{ V or GND}$  | 0 to 5.5          |                           |                   | ±0.1                      |                           | ±1.0                      |                   | ±1.0                      | μΑ   |
| I <sub>CC</sub> | Quiescent Supply<br>Current  | $V_{IN} = V_{CC}$ or GND   | 5.5               |                           |                   | 1.0                       |                           | 10                        |                   | 40                        | μA   |

#### AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3.0 \text{ ns}$ )

|  |   | V <sub>cc</sub> | Test   | Г   | A = 25°C   |             | T <sub>A</sub> ≤ | 85°C        | −55°C t | to 125°C     |      |
|--|---|-----------------|--|-----|------------|-------------|------------------|-------------|---------|--------------|------|
| Symbol                                 | Parameter                                 | (V)             | Conditions                                       | Min | Тур        | Max         | Min              | Max         | Min     | Мах          | Unit |
| t <sub>PLH</sub> ,<br>t <sub>PHL</sub> | Propagation Delay,<br>A to Y              | 3.0 to 3.6      | C <sub>L</sub> = 15 pF<br>C <sub>L</sub> = 50 pF |     | 4.5<br>6.4 | 7.1<br>10.6 |                  | 8.5<br>12.0 |         | 10.0<br>14.5 | ns   |
|  |   | 4.5 to 5.5      | C <sub>L</sub> = 15 pF<br>C <sub>L</sub> = 50 pF |     | 3.5<br>4.5 | 5.5<br>7.5  |                  | 6.5<br>8.5  |         | 8.0<br>10.0  |      |
| C <sub>IN</sub>                        | Input Capacitance                         |                 |  |     | 4.0        | 10          |                  | 10          |         | 10           | pF   |
| C <sub>PD</sub>                        | Power Dissipation<br>Capacitance (Note 6) | 5.0             |  |     | 8.0        |             |                  |             |         |              | pF   |

6. C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I<sub>CC(OPR)</sub> = C<sub>PD</sub> • V<sub>CC</sub> • f<sub>in</sub> + I<sub>CC</sub>. C<sub>PD</sub> is used to determine the no–load dynamic power consumption; P<sub>D</sub> = C<sub>PD</sub> • V<sub>CC</sub><sup>2</sup> • f<sub>in</sub> + I<sub>CC</sub> • V<sub>CC</sub>.

### **NL17SH34**

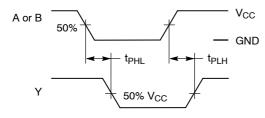


Figure 3. Switching Waveforms

DEVICE UNDER TEST

\*Includes all probe and jig capacitance.

Figure 4. Test Circuit

#### **ORDERING INFORMATION**

| Device        | Device Package       |                    |
|---------------|----------------------|--------------------|
| NL17SH34P5T5G | SOT-953<br>(Pb-Free) | 8000 / Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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SCALE 4:1

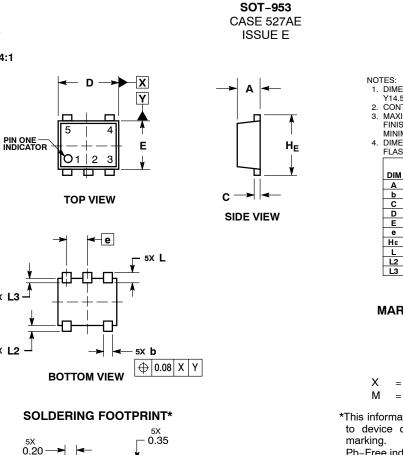
5X L3

5X L2

PACKAGE OUTLINE

0.35 PITCH





#### DATE 02 AUG 2011

NOTES: 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: MILLIMETERS 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL. 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

|     | МІ          | LIMETE      | RS   |  |  |  |  |  |
|-----|-------------|-------------|------|--|--|--|--|--|
| DIM | MIN NOM MAX |             |      |  |  |  |  |  |
| Α   | 0.34        | 0.37        | 0.40 |  |  |  |  |  |
| b   | 0.10        | 0.15        | 0.20 |  |  |  |  |  |
| С   | 0.07        | 0.12        | 0.17 |  |  |  |  |  |
| D   | 0.95        | 1.00        | 1.05 |  |  |  |  |  |
| E   | 0.75        | 5 0.80 0.85 |      |  |  |  |  |  |
| е   |             | 0.35 BS     | С    |  |  |  |  |  |
| HE  | 0.95        | 1.00        | 1.05 |  |  |  |  |  |
| L   | (           | 0.175 RE    | F    |  |  |  |  |  |
| L2  | 0.05        | 0.10        | 0.15 |  |  |  |  |  |
| L3  |             |             | 0.15 |  |  |  |  |  |

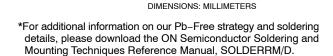
## GENERIC **MARKING DIAGRAM\***

= Specific Device Code

= Month Code

\*This information is generic. Please refer to device data sheet for actual part

Pb-Free indicator, "G" or microdot " .", may or may not be present.



L

1.20

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